

Jiamin Xue

List of Publications by Year in descending order

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22
papers

2,859
citations

758635

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676716

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docs citations

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times ranked

5013
citing authors

#	ARTICLE	IF	CITATIONS
1	Large Photomultiplication by Charge-Self-Trapping for High-Response Quantum Dot Infrared Photodetectors. ACS Applied Materials & Interfaces, 2022, 14, 14783-14790.	4.0	12
2	Anisotropic Infrared Response and Orientation-Dependent Strain-Tuning of the Electronic Structure in Nb ₂ SiTe ₄ . ACS Nano, 2022, 16, 8107-8115.	7.3	7
3	Observation of dimension-crossover of a tunable 1D Dirac fermion in topological semimetal NbSixTe2. Npj Quantum Materials, 2022, 7, .	1.8	7
4	Observation of Γ -Valley Moiré Bands and Emergent Hexagonal Lattice in Twisted Transition Metal Dichalcogenides. Physical Review X, 2022, 12, .	2.8	18
5	Raman spectroscopic study of artificially twisted and non-twisted trilayer graphene. Applied Physics Letters, 2021, 118, .	1.5	3
6	One-Dimensional Metal Embedded in Two-Dimensional Semiconductor in Nb ₂ Si _{1-x} Te ₄ . ACS Nano, 2021, 15, 7149-7154.	7.3	14
7	Visualizing Band Profiles of Gate-Tunable Junctions in MoS ₂ /WSe ₂ Heterostructure Transistors. ACS Nano, 2021, 15, 16314-16321.	7.3	14
8	Detecting band profiles of devices with conductive atomic force microscopy. Review of Scientific Instruments, 2020, 91, 073702.	0.6	7
9	Promotion of CO ₂ Electrochemical Reduction via Cu Nanodendrites. ACS Applied Materials & Interfaces, 2020, 12, 11562-11569.	4.0	54
10	Interlayer Decoupling in 30° Twisted Bilayer Graphene Quasicrystal. ACS Nano, 2020, 14, 1656-1664.	7.3	64
11	Atomic bridge memristor based on silver and two-dimensional GeSe. AIP Advances, 2020, 10, 045003.	0.6	8
12	Nb ₂ SiTe ₄ : A Stable Narrow-Gap Two-Dimensional Material with Ambipolar Transport and Mid-Infrared Response. ACS Nano, 2019, 13, 10705-10710.	7.3	48
13	Isotropic charge screening of anisotropic black phosphorus revealed by potassium adatoms. Physical Review B, 2019, 100, .	1.1	7
14	Systematic investigation of electrical contact barriers between different electrode metals and layered GeSe. Applied Physics Letters, 2019, 114, 013505.	1.5	4
15	Lateral Heterostructures Formed by Thermally Converting n-Type SnSe ₂ to p-Type SnSe. ACS Applied Materials & Interfaces, 2018, 10, 12831-12838.	4.0	37
16	Chemical Vapor Deposition Growth of Bernal-Stacked Bilayer Graphene by Edge-Selective Etching with H ₂ O. Chemistry of Materials, 2018, 30, 7852-7859.	3.2	17
17	Two-Dimensional SnS: A Phosphorene Analogue with Strong In-Plane Electronic Anisotropy. ACS Nano, 2017, 11, 2219-2226.	7.3	239
18	Field-effect transistors of high-mobility few-layer SnSe ₂ . Applied Physics Letters, 2016, 109, .	1.5	73

#	ARTICLE	IF	CITATIONS
19	Graphene on hexagonal boron nitride. <i>Journal of Physics Condensed Matter</i> , 2014, 26, 303201.	0.7	76
20	Long-Wavelength Local Density of States Oscillations Near Graphene Step Edges. <i>Physical Review Letters</i> , 2012, 108, 016801.	2.9	37
21	Emergence of superlattice Dirac points in graphene on hexagonal boron nitride. <i>Nature Physics</i> , 2012, 8, 382-386.	6.5	956
22	Scanning tunnelling microscopy and spectroscopy of ultra-flat graphene on hexagonal boron nitride. <i>Nature Materials</i> , 2011, 10, 282-285.	13.3	1,157